

## Short Biography of Dr. Daniel Tomaszewski:

**Daniel Tomaszewski** (M'2014-SM'2019) received the M.Sc. degree in electronics from Warsaw University of Technology in 1980, the Ph.D. degree in electronics from Institute of Electron Technology, Warsaw in 1998, and the D.Sc. degree from Lodz University of Technology in 2018.

Currently, he is with Łukasiewicz Research Network – Institute of Microelectronics and Photonics (Ł-IMiF), a successor of Institute of Electron Technology, Warsaw. His works include simulation of semiconductor processes and devices, compact modeling and characterization of MOSFETs, BJTs, and sensors, measurements and characterization of semiconductor devices. He is the co-author of many articles and conference presentations related to these topics. He has been serving as a reviewer for a number of journals and conferences, including IEEE Electron Device Letters, IEEE Transactions on Electron Devices, IEEE Journal of the Electron Devices Society, and from 2017 has been a TPC member of ESSDERC conference.

He has been a member of IEEE Electron Devices Society since 2014, and of IEEE Solid-State Circuits Society since 2016. From 2015-2019 he volunteered as EDS Newsletter Regional Editor for Region 8 Eastern Europe. Since 2020 he has been EDS Newsletter Editor-in-Chief.

